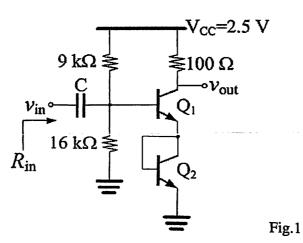
國立東華大學招生考試試題第一月,共2頁

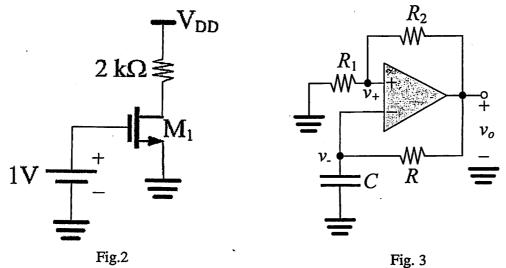
| 招 | 生鸟 | 阜 年 | 度 | 102 | 招 | 生 | 類 | 別 | 碩士班 | |
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| 系 | 所 | 班 | 别 | 光電電子碩士班聯合招生 (光電工程學系碩士班、電機工程學系 電子工程碩士班) | | | | | | |
| 科 | | | 目 | 電子學 | | | | | | |
| 注 | 意 | 事 | 項 | 本考科可使用掌上型計算機 | | | | | | |

1. (10%) A Si pn junction employs $N_A=10^{17}$ cm⁻³ and $N_D=10^{16}$ cm⁻³ (a) Estimate the minority carrier concentrations on both sides at room temperature. (b)Calculate the built-in potential. (c) To obtain a current of 1 mA with a forward bias of 0.7 V, how should the saturation current (I_S) be chosen?

2. (20%) As depicted in Fig.1, $I_{S1}=I_{S2}=5\times10^{-16}$ A, $\beta_1=\beta_2=100$, and $V_A=\infty$. Assume the capacitance (C) is very large. (a) Draw the small-signal equivalent circuit. (b) Find voltage gain (ν_{out}/ν_{in}) . (c) Determine the input impedance (R_{in})



3. (20%) (a) Compute W/L of M_1 in Fig.2 such that the device operates at the edge of saturation. Assume $V_{DD}=1.5$ V, $V_{TH}=0.4$ V, $\lambda=0$, $\mu_n C_{ox}=200$ μ A/V². (b) What happens if the gate oxide thickness is doubled (in triode or saturation? Why?)? Then, what is the voltage gain as a common-source (CS) amplifier?



4. (10%) For the circuit in Fig.3, let the op-amp saturation voltages be ± 10 V, $R_1=100k\Omega$, $R=R_2=1M\Omega$ and $C=0.01\mu F$. Find the frequency of oscillation.

國立東華大學招生考試試題第三頁,共2頁

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| 系 | 所 | 班 | 別 | 光電電子碩士班聯合招生 (光電工程學系碩士班、電機工程學系 電子工程碩士班) | | | | | |
| 科 | | | 且 | 電子學 | | | | | |
| 注 | 意 | 事 | 項 | 本考科可使用掌上型計算機 | | | | | |

- 5. (20%) Design the KHN high-pass filter in Fig.4, with f_0 =10kHz and Q=2. Choose C=1nF and R_1 = R_2 = R_f =10k Ω .
 - (a) What are the values of R and R₃?
 - (b) What is the value of high-frequency gain obtained?

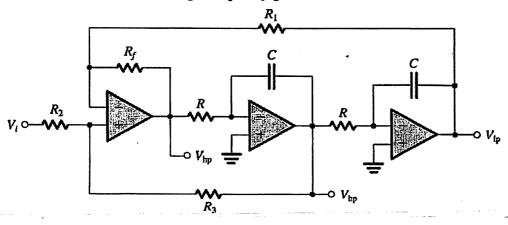


Fig.4

- 6. (5%) Design a CMOS logic gate circuit which performs the function of $Y = \overline{A(B+CD)}$.
- 7. (15%) The cascode amplifier in Fig.5 is operated at a current of 0.2mA with all devices operating at $|V_{OV}| = 0.2V$. All devices have $|V_A| = 2V$.
 - (a) Find g_{m1} and r_{o1} .
 - (b) Find the overall output resistance and the voltage gain realized.

